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[1] Garcia TA and Tamargo MC. Growth and properties of wide bandgap (MgSe)n(ZnxCd1-xSe)m short-period superlattices. J Cryst Growth. 2017;480:74-77.

[2] Hwang J et al. Epitaxial growth of graphitic carbon on C-face SiC and Sapphire by chemical vapor deposition (CVD). J Cryst Growth. 2010;312(21):3219-3224.

[3] Edwards DF, “Silicon (Si)” in *Handbook of optical constants of solids,* E.D. Palik, ed. (Academic, Orlando, Fla. 1985).

[4] Author(s), "Title of paper," in Title of Proceeding, (Institute of Electrical and Electronics Engineers, New York, 1900), pp. 00-00.